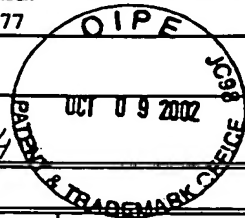


Form PTO 1449 U.S. Department of Commerce Patent and Trademark Office Information Disclosure Statement by Applicant	ATTY. DOCKET NUMBER NITT.0057	SERIAL NUMBER 10/031,377
	APPLICANT SUZUKI et al.	
	FILING DATE April 12, 2002	GROUP 2.674



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	OCT 15 2002
	Technology Center 2600

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10/031377
 JG13 Rec'd PCT/PTO 18 JAN 2002

Form PTO 1449 U.S. Department of Commerce Patent and Trademark Office Information Disclosure Statement by Applicant	ATTY. DOCKET NUMBER		ORIGINAL NUMBER
	NITT.0057		Be Assigned
	APPLICANT		
	SUZUKI et al.		
FILING DATE		GROUP	
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